AMD Xilinx - XCV1600E-8BG560C Datasheet

Welcome to E-XFL.COM

Understanding Embedded - FPGAs (Field Programmable Gate Array)

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications,

Details	
Product Status	Obsolete
Number of LABs/CLBs	7776
Number of Logic Elements/Cells	34992
Total RAM Bits	589824
Number of I/O	404
Number of Gates	2188742
Voltage - Supply	1.71V ~ 1.89V
Mounting Type	Surface Mount
Operating Temperature	0°C ~ 85°C (TJ)
Package / Case	560-LBGA Exposed Pad, Metal
Supplier Device Package	560-MBGA (42.5x42.5)
Purchase URL	https://www.e-xfl.com/product-detail/xilinx/xcv1600e-8bg560c

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong

For in-circuit debugging, an optional download and read-back cable is available. This cable connects the FPGA in the target system to a PC or workstation. After downloading the design into the FPGA, the designer can single-step the logic, readback the contents of the flip-flops, and so observe the internal logic state. Simple modifications can be downloaded into the system in a matter of minutes.

Configuration

Virtex-E devices are configured by loading configuration data into the internal configuration memory. Note that attempting to load an incorrect bitstream causes configuration to fail and can damage the device.

Some of the pins used for configuration are dedicated pins, while others can be re-used as general purpose inputs and outputs once configuration is complete.

The following are dedicated pins:

- Mode pins (M2, M1, M0)
- Configuration clock pin (CCLK)
- $\overline{\text{PROGRAM}}$ pin
- DONE pin
- Boundary Scan pins (TDI, TDO, TMS, TCK)

Depending on the configuration mode chosen, CCLK can be an output generated by the FPGA, or can be generated externally and provided to the FPGA as an input. The $\overline{\text{PROGRAM}}$ pin must be pulled High prior to reconfiguration.

Note that some configuration pins can act as outputs. For correct operation, these pins require a V_{CCO} of 3.3 V or 2.5 V. At 3.3 V the pins operate as LVTTL, and at 2.5 V they operate as LVCMOS. All affected pins fall in banks 2 or 3. The configuration pins needed for SelectMap (CS, Write) are located in bank 1.

Configuration Modes

Virtex-E supports the following four configuration modes.

- Slave-serial mode
- Master-serial mode
- SelectMAP mode
- Boundary Scan mode (JTAG)

The Configuration mode pins (M2, M1, M0) select among these configuration modes with the option in each case of having the IOB pins either pulled up or left floating prior to configuration. The selection codes are listed in Table 8.

Configuration through the Boundary Scan port is always available, independent of the mode selection. Selecting the Boundary Scan mode simply turns off the other modes. The three mode pins have internal pull-up resistors, and default to a logic High if left unconnected. However, it is recommended to drive the configuration mode pins externally.

Table 8: **Configuration Codes**

Configuration Mode	M2(1)	M1	M0	CCLK Direction	Data Width	Serial D_{out}	Configuration Pull-ups(1)
Master-serial mode	0	0	0	Out	1	Yes	No
Boundary Scan mode	1	0	1	N/A	1	No	No
SelectMAP mode	1	1	0	In	8	No	No
Slave-serial mode	1	1	1	In	1	Yes	No
Master-serial mode	1	0	0	Out	1	Yes	Yes
Boundary Scan mode	0	0	1	N/A	1	No	Yes
SelectMAP mode	0	1	0	In	8	No	Yes
Slave-serial mode	0	1	1	In	1	Yes	Yes

Notes:
1. M2 is sampled continuously from power up until the end of the configuration. Toggling M2 while INIT is being held externally Low can cause the configuration pull-up settings to change.

Table 9 lists the total number of bits required to configure each device.

Table 9: **Virtex-E Bitstream Lengths**

Device	# of Configuration Bits
XCV50E	630,048
XCV100E	863,840
XCV200E	1,442,016
XCV300E	1, 875,648
XCV400E	2,693,440
XCV600E	3,961,632
XCV1000E	6,587,520
XCV1600E	8,308,992
XCV2000E	10,159,648
XCV2600E	12,922,336
XCV3200E	16,283,712

Slave-Serial Mode

In slave-serial mode, the FPGA receives configuration data in bit-serial form from a serial PROM or other source of serial configuration data. The serial bitstream must be set up at the DIN input pin a short time before each rising edge of an externally generated CCLK.

For more detailed information on serial PROMs, see the PROM data sheet at http://www.xilinx.com/bvdocs/publications/ds026.pdf.

Multiple FPGAs can be daisy-chained for configuration from a single source. After a particular FPGA has been configured, the data for the next device is routed to the DOUT pin. The maximum capacity for a single LOUT/DOUT write is 2^{20}-1 (1,048,575) 32-bit words, or 33,554,4000 bits. The data on the DOUT pin changes on the rising edge of CCLK.

The change of DOUT on the rising edge of CCLK differs from previous families, but does not cause a problem for mixed configuration chains. This change was made to improve serial configuration rates for Virtex and Virtex-E only chains.

Figure 13 shows a full master/slave system. A Virtex-E device in slave-serial mode should be connected as shown in the right-most device.

Slave-serial mode is selected by applying <111> or <011> to the mode pins (M2, M1, M0). A weak pull-up on the mode pins makes slave serial the default mode if the pins are left unconnected. However, it is recommended to drive the configuration mode pins externally. Figure 14 shows slave-serial mode programming switching characteristics.

Table 10 provides more detail about the characteristics shown in Figure 14. Configuration must be delayed until the $\overline{\text{INIT}}$ pins of all daisy-chained FPGAs are High.

Table 10: **Master/Slave Serial Mode Programming Switching**

	Description	Figure References	Symbol	Values	Units
CCLK	DIN setup/hold, slave mode	1/2	T_{DCC}/T_{CCD}	5.0 / 0.0	ns, min
	DIN setup/hold, master mode	1/2	T_{DSCK}/T_{CKDS}	5.0 / 0.0	ns, min
	DOUT	3	T_{CCO}	12.0	ns, max
	High time	4	T_{CCH}	5.0	ns, min
	Low time	5	T_{CCL}	5.0	ns, min
	Maximum Frequency		F_{CC}	66	MHz, max
	Frequency Tolerance, master mode with respect to nominal			+45% –30%	

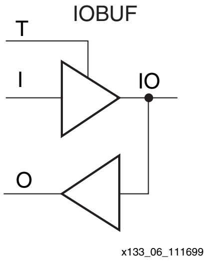

Figure 42: **Input/Output Buffer Symbol (IOBUF)**

The following list details variations of the IOBUF symbol.

- IOBUF
- IOBUF_S_2
- IOBUF_S_4
- IOBUF_S_6
- IOBUF_S_8
- IOBUF_S_12
- IOBUF_S_16
- IOBUF_S_24
- IOBUF_F_2
- IOBUF_F_4
- IOBUF_F_6
- IOBUF_F_8
- IOBUF_F_12
- IOBUF_F_16
- IOBUF_F_24
- IOBUF_LVCMOS2
- IOBUF_PCI33_3
- IOBUF_PCI66_3
- IOBUF_GTL
- IOBUF_GTLP
- IOBUF_HSTL_I
- IOBUF_HSTL_III
- IOBUF_HSTL_IV
- IOBUF_SSTL3_I
- IOBUF_SSTL3_II
- IOBUF_SSTL2_I
- IOBUF_SSTL2_II
- IOBUF_CTT
- IOBUF_AGP
- IOBUF_LVCMOS18
- IOBUF_LVDS
- IOBUF_LVPECL

When the IOBUF symbol used supports an I/O standard that requires a differential amplifier input, the IOBUF automatically configures with a differential amplifier input buffer. The low-voltage I/O standards with a differential amplifier input require an external reference voltage input V_{REF}.

The voltage reference signal is "banked" within the Virtex-E device on a half-edge basis such that for all packages there are eight independent V_{REF} banks internally. See Figure 38, page 34 for a representation of the Virtex-E I/O banks. Within each bank approximately one of every six I/O pins is automatically configured as a V_{REF} input. After placing a differential amplifier input signal within a given V_{REF} bank, the same external source must drive all I/O pins configured as a V_{REF} input.

IOBUF placement restrictions require any differential amplifier input signals within a bank be of the same standard.

The Virtex-E series supports eight banks for the HQ and PQ packages. The CS package supports four V_{CCO} banks.

Additional restrictions on the Virtex-E SelectI/O IOBUF placement require that within a given V_{CCO} bank each IOBUF must share the same output source drive voltage. Input buffers of any type and output buffers that do not require V_{CCO} can be placed within the same V_{CCO} bank. The LOC property can specify a location for the IOBUF.

An optional delay element is associated with the input path in each IOBUF. When the IOBUF drives an input flip-flop within the IOB, the delay element activates by default to ensure a zero hold-time requirement. Override this default with the NODELAY=TRUE property.

In the case when the IOBUF does not drive an input flip-flop within the IOB, the delay element de-activates by default to provide higher performance. To delay the input signal, activate the delay element with the DELAY=TRUE property.

3-state output buffers and bidirectional buffers can have either a weak pull-up resistor, a weak pull-down resistor, or a weak "keeper" circuit. Control this feature by adding the appropriate symbol to the output net of the IOBUF (PULLUP, PULLDOWN, or KEEPER).

SelectI/O Properties

Access to some of the SelectI/O features (for example, location constraints, input delay, output drive strength, and slew rate) is available through properties associated with these features.

Input Delay Properties

An optional delay element is associated with each IBUF. When the IBUF drives a flip-flop within the IOB, the delay element activates by default to ensure a zero hold-time requirement. Use the NODELAY=TRUE property to override this default.

In the case when the IBUF does not drive a flip-flop within the IOB, the delay element by default de-activates to provide higher performance. To delay the input signal, activate the delay element with the DELAY=TRUE property.

Application Examples

Creating a design with the SelectI/O features requires the instantiation of the desired library symbol within the design code. At the board level, designers need to know the termination techniques required for each I/O standard.

This section describes some common application examples illustrating the termination techniques recommended by each of the standards supported by the SelectI/O features.

Termination Examples

Circuit examples involving typical termination techniques for each of the SelectI/O standards follow. For a full range of accepted values for the DC voltage specifications for each standard, refer to the table associated with each figure.

The resistors used in each termination technique example and the transmission lines depicted represent board level components and are not meant to represent components on the device.

GTL

A sample circuit illustrating a valid termination technique for GTL is shown in Figure 44.

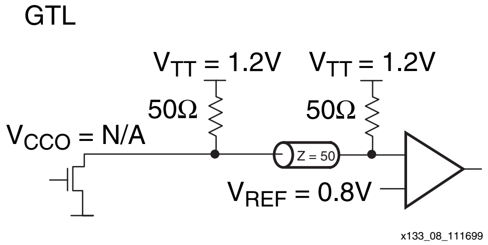

Figure 44: **Terminated GTL**

Table 23 lists DC voltage specifications.

Table 23: **GTL Voltage Specifications**

Parameter	Min	Typ	Max
V_{CCO}	-	N/A	-
$V_{REF} = N \times V_{TT}$[1]	0.74	0.8	0.86
V_{TT}	1.14	1.2	1.26
$V_{IH} = V_{REF} + 0.05$	0.79	0.85	-
$V_{IL} = V_{REF} - 0.05$	-	0.75	0.81
V_{OH}	-	-	-
V_{OL}	-	0.2	0.4
I_{OH} at V_{OH}(mA)	-	-	-
I_{OL}at V_{OL}(mA) at 0.4V	32	-	-
I_{OL}at V_{OL}(mA) at 0.2V	-	-	40

Notes:

1. N must be greater than or equal to 0.653 and less than or equal to 0.68.

GTL+

A sample circuit illustrating a valid termination technique for GTL+ appears in Figure 45. DC voltage specifications appear in Table 24.

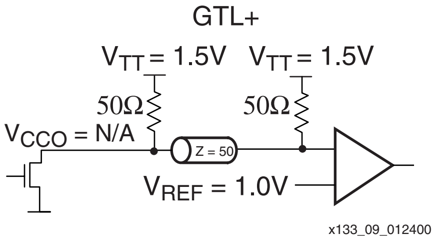

Figure 45: **Terminated GTL+**

Table 24: **GTL+ Voltage Specifications**

Parameter	Min	Typ	Max
V_{CCO}	-	-	-
$V_{REF} = N \times V_{TT}$[1]	0.88	1.0	1.12
V_{TT}	1.35	1.5	1.65
$V_{IH} = V_{REF} + 0.1$	0.98	1.1	-
$V_{IL} = V_{REF} - 0.1$	-	0.9	1.02
V_{OH}	-	-	-
V_{OL}	0.3	0.45	0.6
I_{OH} at V_{OH} (mA)	-	-	-
I_{OL}at V_{OL} (mA) at 0.6V	36	-	-
I_{OL}at V_{OL} (mA) at 0.3V	-	-	48

Notes:

1. N must be greater than or equal to 0.653 and less than or equal to 0.68.

The register elements can be packed in the IOB using the IOB property to TRUE on the register or by using the “map -pr [i|o|b]” where “i” is inputs only, “o” is outputs only and “b” is both inputs and outputs.

To improve design coding times VHDL and Verilog synthesis macro libraries have been developed to explicitly create these structures. The input library macros are listed below. The 3-state is configured to be 3-stated at GSR and when the PRE,CLR,S or R is asserted and shares it's clock enable with the output register. If this is not desirable then the library can be updated by the user for the desired functionality. The O and OB inputs to the macros are the external net connections.

Creating a LVDS Bidirectional Buffer

LVDS bidirectional buffers can be placed in a wide number of IOB locations. The exact locations are dependent on the package used. The Virtex-E package information lists the possible locations as IO_L#P for the P-side and IO_L#N for the N-side, where # is the pair number.

HDL Instantiation

Both bidirectional buffers are required to be instantiated in the design and placed on the correct IO_L#P and IO_L#N locations. The IOB must have the same net source the following pins, clock (C), set/reset (SR), 3-state (T), 3-state clock enable (TCE), output (O), output clock enable (OCE). In addition, the output (O) pins must be inverted with respect to each other, and if output registers are used, the INIT states must be opposite values (one HIGH and one LOW). If 3-state registers are used, they must be initialized to the same state. Failure to follow these rules leads to DRC errors in the software.

VHDL Instantiation

```
data0_p:   IOBUF_LVDS port map
(I=>data_out(0), T=>data_tri,
IO=>data_p(0), O=>data_int(0));

data0_inv: INV        port map
(I=>data_out(0),   O=>data_n_out(0));

data0_n   : IOBUF_LVDS port map
(I=>data_n_out(0), T=>data_tri,
IO=>data_n(0), O=>open);
```

Verilog Instantiation

```
IOBUF_LVDS data0_p(.I(data_out[0]),
.T(data_tri), .IO(data_p[0]),
.O(data_int[0]);

INV        data0_inv (.I(data_out[0],
.O(data_n_out[0]);

IOBUF_LVDS
data0_n(.I(data_n_out[0]),.T(data_tri),.
IO(data_n[0]).O());
```

Location Constraints

All LVDS buffers must be explicitly placed on a device. For the output buffers this can be done with the following constraint in the .ucf or .ncf file.

```
NET data_p<0> LOC = D28; # IO_L0P

NET data_n<0> LOC = B29; # IO_L0N
```

Synchronous vs. Asynchronous Bidirectional Buffers

If the output side of the bidirectional buffers are synchronous (registered in the IOB), then any IO_L#P|N pair can be used. If the output side of the bidirectional buffers are asynchronous (no output register), then they must use one of the pairs that is a part of the asynchronous LVDS IOB group. This applies for either the 3-state pin or the data out pin.

The LVDS pairs that can be used as asynchronous bidirectional buffers are listed in the Virtex-E pinout tables. Some pairs are marked as asynchronous capable for all devices in that package, and others are marked as available only for that device in the package. If the device size might change at some point in the product’s lifetime, then only the common pairs for all packages should be used.

Adding Output and 3-State Registers

All LVDS buffers can have an output and input registers in the IOB. The output registers must be in both the P-side and N-side IOBs, the input register is only in the P-side. All the normal IOB register options are available (FD, FDE, FDC, FDCE, FDP, FDPE, FDR, FDRE, FDS, FDSE, LD, LDE, LDC, LDCE, LDP, LDPE). The register elements can be inferred or explicitly instantiated in the HDL code. Special care must be taken to insure that the D pins of the registers are inverted and that the INIT states of the registers are opposite. The 3-state (T), 3-state clock enable (CE), clock pin (C), output clock enable (CE), and set/reset (CLR/PRE or S/R) pins must connect to the same source. Failure to do this leads to a DRC error in the software.

The register elements can be packed in the IOB using the IOB property to TRUE on the register or by using the “map -pr [i|o|b]” where “i” is inputs only, “o” is outputs only and “b” is both inputs and outputs. To improve design coding times VHDL and Verilog synthesis macro libraries have been developed to explicitly create these structures. The bidirectional I/O library macros are listed in Table 44. The 3-state is configured to be 3-stated at GSR and when the PRE,CLR,S or R is asserted and shares its clock enable with the output and input register. If this is not desirable then the library can be updated be the user for the desired functionality. The I/O and IOB inputs to the macros are the external net connections.

Power-On Power Supply Requirements

Xilinx FPGAs require a certain amount of supply current during power-on to insure proper device operation. The actual current consumed depends on the power-on ramp rate of the power supply. This is the time required to reach the nominal power supply voltage of the device[1] from 0V. The fastest ramp rate is 0V to nominal voltage in 2 ms, and the slowest allowed ramp rate is 0V to nominal voltage in 50 ms. For more details on power supply requirements, see XAPP158 on www.xilinx.com.

Product (Commercial Grade)	Description(2)	Current Requirement(3)
XCV50E - XCV600E	Minimum required current supply	500 mA
XCV812E - XCV2000E	Minimum required current supply	1 A
XCV2600E - XCV3200E	Minimum required current supply	1.2 A
Virtex-E Family, Industrial Grade	Minimum required current supply	2 A

Notes:

1. Ramp rate used for this specification is from 0 - 1.8 V DC. Peak current occurs on or near the internal power-on reset threshold and lasts for less than 3 ms.
2. Devices are guaranteed to initialize properly with the minimum current available from the power supply as noted above.
3. Larger currents might result if ramp rates are forced to be faster.

DC Input and Output Levels

Values for V_{IL} and V_{IH} are recommended input voltages. Values for I_{OL} and I_{OH} are guaranteed over the recommended operating conditions at the V_{OL} and V_{OH} test points. Only selected standards are tested. These are chosen to ensure that all standards meet their specifications. The selected standards are tested at minimum V_{CCO} with the respective V_{OL} and V_{OH} voltage levels shown. Other standards are sample tested.

Input/Output Standard	V_{IL}		V_{IH}		V_{OL}	V_{OH}	I_{OL}	I_{OH}
	V, Min	V, Max	V, Min	V, Max	V, Max	V, Min	mA	mA
LVTTL(1)	– 0.5	0.8	2.0	3.6	0.4	2.4	24	– 24
LVCMOS2	– 0.5	0.7	1.7	2.7	0.4	1.9	12	– 12
LVCMOS18	– 0.5	35% V_{CCO}	65% V_{CCO}	1.95	0.4	V_{CCO} – 0.4	8	– 8
PCI, 3.3 V	– 0.5	30% V_{CCO}	50% V_{CCO}	V_{CCO} + 0.5	10% V_{CCO}	90% V_{CCO}	Note 2	Note 2
GTL	– 0.5	V_{REF} – 0.05	V_{REF} + 0.05	3.6	0.4	n/a	40	n/a
GTL+	– 0.5	V_{REF} – 0.1	V_{REF} + 0.1	3.6	0.6	n/a	36	n/a
HSTL I(3)	– 0.5	V_{REF} – 0.1	V_{REF} + 0.1	3.6	0.4	V_{CCO} – 0.4	8	–8
HSTL III	– 0.5	V_{REF} – 0.1	V_{REF} + 0.1	3.6	0.4	V_{CCO} – 0.4	24	–8
HSTL IV	– 0.5	V_{REF} – 0.1	V_{REF} + 0.1	3.6	0.4	V_{CCO} – 0.4	48	–8
SSTL3 I	– 0.5	V_{REF} – 0.2	V_{REF} + 0.2	3.6	V_{REF} – 0.6	V_{REF} + 0.6	8	–8
SSTL3 II	– 0.5	V_{REF} – 0.2	V_{REF} + 0.2	3.6	V_{REF} – 0.8	V_{REF} + 0.8	16	–16
SSTL2 I	– 0.5	V_{REF} – 0.2	V_{REF} + 0.2	3.6	V_{REF} – 0.61	V_{REF} + 0.61	7.6	–7.6
SSTL2 II	– 0.5	V_{REF} – 0.2	V_{REF} + 0.2	3.6	V_{REF} – 0.80	V_{REF} + 0.80	15.2	–15.2

Block RAM Switching Characteristics

		Speed Grade[1]				
Description	**Symbol**	**Min**	**-8**	**-7**	**-6**	**Units**
Sequential Delays						
Clock CLK to DOUT output	T_{BCKO}	0.63	2.46	3.1	3.5	ns, max
Setup and Hold Times before Clock CLK						
ADDR inputs	T_{BACK}/T_{BCKA}	0.42 / 0	0.9 / 0	1.0 / 0	1.1 / 0	ns, min
DIN inputs	T_{BDCK}/T_{BCKD}	0.42 / 0	0.9 / 0	1.0 / 0	1.1 / 0	ns, min
EN input	T_{BECK}/T_{BCKE}	0.97 / 0	2.0 / 0	2.2 / 0	2.5 / 0	ns, min
RST input	T_{BRCK}/T_{BCKR}	0.9 / 0	1.8 / 0	2.1 / 0	2.3 / 0	ns, min
WEN input	T_{BWCK}/T_{BCKW}	0.86 / 0	1.7 / 0	2.0 / 0	2.2 / 0	ns, min
Clock CLK						
Minimum Pulse Width, High	T_{BPWH}	0.6	1.2	1.35	1.5	ns, min
Minimum Pulse Width, Low	T_{BPWL}	0.6	1.2	1.35	1.5	ns, min
CLKA -> CLKB setup time for different ports	T_{BCCS}	1.2	2.4	2.7	3.0	ns, min

Notes:

1. A Zero “0” Hold Time listing indicates no hold time or a negative hold time. Negative values can not be guaranteed “best-case”, but if a “0” is listed, there is no positive hold time.

TBUF Switching Characteristics

		Speed Grade				
Description	**Symbol**	**Min**	**-8**	**-7**	**-6**	**Units**
Combinatorial Delays						
IN input to OUT output	T_{IO}	0.0	0.0	0.0	0 .0	ns, max
TRI input to OUT output high-impedance	T_{OFF}	0.05	0.092	0.10	0.11	ns, max
TRI input to valid data on OUT output	T_{ON}	0.05	0.092	0.10	0.11	ns, max

JTAG Test Access Port Switching Characteristics

Description	Symbol	Value	Units
TMS and TDI Setup times before TCK	T_{TAPTK}	4.0	ns, min
TMS and TDI Hold times after TCK	T_{TCKTAP}	2.0	ns, min
Output delay from clock TCK to output TDO	T_{TCKTDO}	11.0	ns, max
Maximum TCK clock frequency	F_{TCK}	33	MHz, max

Virtex-E Pin-to-Pin Output Parameter Guidelines

All devices are 100% functionally tested. Listed below are representative values for typical pin locations and normal clock loading. Values are expressed in nanoseconds unless otherwise noted.

Global Clock Input to Output Delay for LVTTL, 12 mA, Fast Slew Rate, *with* DLL

Description(1)	Symbol	Device	Speed Grade(2, 3) Min	-8	-7	-6	Units
LVTTL Global Clock Input to Output Delay using Output Flip-flop, 12 mA, Fast Slew Rate, *with* DLL. For data *output* with different standards, adjust the delays with the values shown in **IOB Output Switching Characteristics Standard Adjustments**, page 10.	$T_{ICKOFDLL}$	XCV50E	1.0	3.1	3.1	3.1	ns
		XCV100E	1.0	3.1	3.1	3.1	ns
		XCV200E	1.0	3.1	3.1	3.1	ns
		XCV300E	1.0	3.1	3.1	3.1	ns
		XCV400E	1.0	3.1	3.1	3.1	ns
		XCV600E	1.0	3.1	3.1	3.1	ns
		XCV1000E	1.0	3.1	3.1	3.1	ns
		XCV1600E	1.0	3.1	3.1	3.1	ns
		XCV2000E	1.0	3.1	3.1	3.1	ns
		XCV2600E	1.0	3.1	3.1	3.1	ns
		XCV3200E	1.0	3.1	3.1	3.1	ns

Notes:

1. Listed above are representative values where one global clock input drives one vertical clock line in each accessible column, and where all accessible IOB and CLB flip-flops are clocked by the global clock net.
2. Output timing is measured at 50% V_{CC} threshold with 35 pF external capacitive load. For other I/O standards and different loads, see Table 3 and Table 4.
3. DLL output jitter is already included in the timing calculation.

DLL Clock Tolerance, Jitter, and Phase Information

All DLL output jitter and phase specifications determined through statistical measurement at the package pins using a clock mirror configuration and matched drivers.

			CLKDLLHF		CLKDLL		Units
Description	**Symbol**	**F_{CLKIN}**	**Min**	**Max**	**Min**	**Max**	
Input Clock Period Tolerance	T_{IPTOL}		-	1.0	-	1.0	ns
Input Clock Jitter Tolerance (Cycle to Cycle)	T_{IJITCC}		-	± 150	-	± 300	ps
Time Required for DLL to Acquire Lock(6)	T_{LOCK}	> 60 MHz	-	20	-	20	µs
		50 - 60 MHz	-	-	-	25	µs
		40 - 50 MHz	-	-	-	50	µs
		30 - 40 MHz	-	-	-	90	µs
		25 - 30 MHz	-	-	-	120	µs
Output Jitter (cycle-to-cycle) for any DLL Clock Output(1)	T_{OJITCC}			± 60		± 60	ps
Phase Offset between CLKIN and CLKO(2)	T_{PHIO}			± 100		± 100	ps
Phase Offset between Clock Outputs on the DLL(3)	T_{PHOO}			± 140		± 140	ps
Maximum Phase Difference between CLKIN and CLKO(4)	T_{PHIOM}			± 160		± 160	ps
Maximum Phase Difference between Clock Outputs on the DLL(5)	T_{PHOOM}			± 200		± 200	ps

Notes:

1. **Output Jitter** is cycle-to-cycle jitter measured on the DLL output clock and is based on a maximum tap delay resolution, *excluding* input clock jitter.
2. **Phase Offset between CLKIN and CLKO** is the worst-case fixed time difference between rising edges of CLKIN and CLKO, *excluding* Output Jitter and input clock jitter.
3. **Phase Offset between Clock Outputs on the DLL** is the worst-case fixed time difference between rising edges of any two DLL outputs, *excluding* Output Jitter and input clock jitter.
4. **Maximum Phase Difference between CLKIN an CLKO** is the sum of Output Jitter and Phase Offset between CLKIN and CLKO, or the greatest difference between CLKIN and CLKO rising edges due to DLL alone (*excluding* input clock jitter).
5. **Maximum Phase DIfference between Clock Outputs on the DLL** is the sum of Output JItter and Phase Offset between any DLL clock outputs, or the greatest difference between any two DLL output rising edges sue to DLL alone (*excluding* input clock jitter).
6. Add 30% to the value for industrial grade parts.

Table 8: **HQ240 — XCV600E, XCV1000E**

Pin #	Pin Description	Bank
P210	GCK2	1
P209	IO_LVDS_DLL_L6P	1
P208	IO_VREF	1
P207	VCCO	1
P206	IO_L7N_Y	1
P205	IO_VREF_L7P_Y	1
P204	GND	NA
P203	IO_L8N_Y	1
P202	IO_L8P_Y	1
P201[1]	IO_VREF	1
P200	IO_L9N_YY	1
P199	IO_L9P_YY	1
P198	VCCINT	NA
P197	VCCO	1
P196	GND	NA
P195	IO_L10N_YY	1
P194	IO_VREF_L10P_YY	1
P193	IO_VREF	1
P192	IO_L11N_YY	1
P191	IO_VREF_L11P_YY	1
P190	GND	NA
P189	IO_L12N_YY	1
P188	IO_L12P_YY	1
P187	IO_VREF_L13N	1
P186	IO_L13P	1
P185	IO_WRITE_L14N_YY	1
P184	IO_CS_L14P_YY	1
P183	TDI	NA
P182	GND	NA
P181	TDO	2
P180	VCCO	1
P179	CCLK	2
P178	IO_DOUT_BUSY_L15P_YY	2
P177	IO_DIN_D0_L15N_YY	2
P176	VCCO	2
P175	IO_VREF	2

Table 8: **HQ240 — XCV600E, XCV1000E**

Pin #	Pin Description	Bank
P174	IO_L16P_Y	2
P173	IO_L16N_Y	2
P172	GND	NA
P171	IO_VREF_L17P_Y	2
P170	IO_L17N_Y	2
P169	IO_VREF	2
P168	IO_VREF_L18P_Y	2
P167	IO_D1_L18N_Y	2
P166	GND	NA
P165	VCCO	2
P164	VCCINT	NA
P163	IO_D2_L19P_YY	2
P162	IO_L19N_YY	2
P161[1]	IO_VREF	2
P160	IO_L20P_Y	2
P159	IO_L20N_Y	2
P158	GND	NA
P157	IO_VREF_L21P_Y	2
P156	IO_D3_L21N_Y	2
P155	IO_L22P_Y	2
P154	IO_VREF_L22N_Y	2
P153	IO_L23P_YY	2
P152	IO_L23N_YY	2
P151	GND	NA
P150	VCCO	2
P149	IO	3
P148	VCCINT	NA
P147	IO_VREF	3
P146	VCCO	3
P145	IO_D4_L24P_Y	3
P144	IO_VREF_L24N_Y	3
P143	GND	NA
P142	IO_L25P_Y	3
P141	IO_L25N_Y	3
P140[1]	IO_VREF	3
P139	IO_L26P_YY	3

Table 8: **HQ240 — XCV600E, XCV1000E**

Pin #	Pin Description	Bank
P66	IO_VREF_L46P	5
P65	IO_L46N	5
P64	IO_L47P_YY	5
P63	IO_L47N_YY	5
P62	M2	NA
P61	VCCO	5
P60	M0	NA
P59	GND	NA
P58	M1	NA
P57	IO_L48N_YY	6
P56	IO_L48P_YY	6
P55	VCCO	6
P54	IO_VREF	6
P53	IO_L49N_Y	6
P52	IO_L49P_Y	6
P51	GND	NA
P50	IO_VREF_L50N_Y	6
P49	IO_L50P_Y	6
P48	IO_VREF	6
P47	IO_VREF_L51N_Y	6
P46	IO_L51P_Y	6
P45	GND	NA
P44	VCCO	6
P43	VCCINT	NA
P42	IO_L52N_YY	6
P41	IO_L52P_YY	6
P40[1]	IO_VREF	6
P39	IO_L53N_Y	6
P38	IO_L53P_Y	6
P37	GND	NA
P36	IO_VREF_L54N_Y	6
P35	IO_L54P_Y	6
P34	IO_L55N_Y	6
P33	IO_VREF_L55P_Y	6
P32	VCCINT	NA
P31	IO	6
P30	VCCO	6
P29	GND	NA
P28	IO_L56N_YY	7
P27	IO_L56P_YY	7
P26	IO_VREF	7
P25	VCCO	7
P24	IO_L57N_Y	7
P23	IO_VREF_L57P_Y	7
P22	GND	NA
P21	IO_L58N_Y	7
P20	IO_L58P_Y	7
P19[1]	IO_VREF	7
P18	IO_L59N_YY	7
P17	IO_L59P_YY	7
P16	VCCINT	NA
P15	VCCO	7
P14	GND	NA
P13	IO_L60N_Y	7
P12	IO_VREF_L60P_Y	7
P11	IO_VREF	7
P10	IO_L61N_Y	7
P9	IO_VREF_L61P_Y	7
P8	GND	NA
P7	IO_L62N_Y	7
P6	IO_L62P_Y	7
P5	IO_VREF_L63N_Y	7
P4	IO_L63P_Y	7
P3	IO	7
P2	TMS	NA
P1	GND	NA

Notes:

1. V_{REF} or I/O option only in the XCV1000E; otherwise, I/O option only.

BG352 Differential Pin Pairs

Virtex-E devices have differential pin pairs that can also provide other functions when not used as a differential pair. A check (√) in the AO column indicates that the pin pair can be used as an asynchronous output for all devices provided in this package. Pairs with a note number in the AO column are device dependent. They can have asynchronous outputs if the pin pair are in the same CLB row and column in the device. Numbers in this column refer to footnotes that indicate which devices have pin pairs than can be asynchronous outputs. The Other Functions column indicates alternative function(s) not available when the pair is used as a differential pair or differential clock

Table 11: **BG352 Differential Pin Pair Summary XCV100E, XCV200E, XCV300E**

Pair	Bank	P Pin	N Pin	AO	Other Functions
Global Differential Clock					
0	4	AE13	AC13	NA	IO LVDS 55
1	5	AF14	AD14	NA	IO LVDS 55
2	1	B14	A13	NA	IO LVDS 9
3	0	D14	A15	NA	IO LVDS 9
IO LVDS Total Outputs: 87, Asynchronous Output Pairs: 43					
0	0	B23	D21	√	VREF_0
1	0	D20	A23	√	-
2	0	B22	C21	√	VREF_0
3	0	A21	B20	2	-
4	0	B19	C19	√	VREF_0
5	0	C18	D17	√	-
6	0	A18	C17	2	-
7	0	C16	B17	√	-
8	0	D15	A16	√	VREF_0
9	1	A13	A15	√	GCLK LVDS 3/2
10	1	A12	C13	2	-
11	1	C12	B12	√	VREF_1
12	1	B11	A11	√	-
13	1	D11	C11	2	-
14	1	C10	B9	√	-
15	1	C9	B8	√	VREF_1
16	1	A7	D9	1	-
17	1	B6	A6	√	VREF_1
18	1	A4	C7	√	-
19	1	D6	C6	√	VREF_1
20	1	C4	D5	√	CS
21	2	E4	D3	√	DIN_D0
22	2	D2	C1	√	VREF_2
23	2	G4	F3	√	-
24	2	E2	F2	√	VREF_2
25	2	F1	J4	2	-
26	2	H2	G1	√	D1
27	2	J3	J2	√	D2
28	2	J1	L4	1	-
29	2	L3	L2	√	-
30	2	M4	M3	√	D3
31	2	M2	M1	2	-
32	2	N4	N2	√	-
33	3	R1	R2	2	-
34	3	R3	R4	√	VREF_3
35	3	T2	U2	√	-
36	3	T4	V1	1	-
37	3	U3	U4	√	D5
38	3	V3	V4	√	VREF_3
39	3	Y1	Y2	1	-
40	3	AA2	Y3	√	VREF_3
41	3	AC1	AB2	√	-
42	3	AA4	AC2	√	VREF_3
43	3	AC3	AD2	√	INIT
44	4	AC5	AD4	√	-
45	4	AE4	AF3	√	VREF_4
46	4	AC7	AD6	√	-
47	4	AE5	AE6	√	VREF_4
48	4	AF6	AC9	2	-
49	4	AE8	AF7	√	VREF_4
50	4	AD9	AE9	√	-
51	4	AF9	AC11	2	-
52	4	AD11	AE11	√	-
53	4	AC12	AD12	√	VREF_4
54	4	AE12	AF12	2	-

Table 14: **BG560 — XCV400E, XCV600E, XCV1000E, XCV1600E, XCV2000E**

Bank	Pin Description	Pin#	See Note
1	IO_L43N_Y	C5	
1	IO_VREF_L43P_Y	E7	3
1	IO_WRITE_L44N_YY	D6	
1	IO_CS_L44P_YY	A2	
2	IO	D3	
2	IO	F3	
2	IO	G1	
2	IO	J2	
2	IO_DOUT_BUSY_L45P_YY	D4	
2	IO_DIN_D0_L45N_YY	E4	
2	IO_L46P_Y	F5	
2	IO_VREF_L46N_Y	B3	3
2	IO_L47P_Y	F4	
2	IO_L47N_Y	C1	
2	IO_VREF_L48P_Y	G5	
2	IO_L48N_Y	E3	
2	IO_L49P_Y	D2	
2	IO_L49N_Y	G4	
2	IO_L50P_Y	H5	
2	IO_L50N_Y	E2	
2	IO_VREF_L51P_YY	H4	
2	IO_L51N_YY	G3	
2	IO_L52P_Y	J5	
2	IO_VREF_L52N_Y	F1	1
2	IO_L53P_Y	J4	
2	IO_L53N_Y	H3	
2	IO_VREF_L54P_Y	K5	4
2	IO_L54N_Y	H2	
2	IO_L55P_Y	J3	
2	IO_L55N_Y	K4	
2	IO_VREF_L56P_YY	L5	
2	IO_D1_L56N_YY	K3	
2	IO_D2_L57P_YY	L4	
2	IO_L57N_YY	K2	
2	IO_L58P_Y	M5	
2	IO_L58N_Y	L3	
2	IO_L59P_Y	L1	
2	IO_L59N_Y	M4	
2	IO_VREF_L60P_Y	N5	3
2	IO_L60N_Y	M2	
2	IO_L61P_Y	N4	
2	IO_L61N_Y	N3	
2	IO_L62P_Y	N2	
2	IO_L62N_Y	P5	
2	IO_VREF_L63P_YY	P4	
2	IO_D3_L63N_YY	P3	
2	IO_L64P_Y	P2	
2	IO_L64N_Y	R5	
2	IO_L65P_Y	R4	
2	IO_L65N_Y	R3	
2	IO_VREF_L66P_Y	R1	
2	IO_L66N_Y	T4	
2	IO_L67P_Y	T5	
2	IO_VREF_L67N_Y	T3	2
2	IO_L68P_YY	T2	
2	IO_L68N_YY	U3	
3	IO	AE3	
3	IO	AF3	
3	IO	AH3	
3	IO	AK3	
3	IO_VREF_L69P_Y	U1	2
3	IO_L69N_Y	U2	
3	IO_L70P_Y	V2	
3	IO_VREF_L70N_Y	V4	
3	IO_L71P_Y	V5	
3	IO_L71N_Y	V3	
3	IO_L72P_Y	W1	
3	IO_L72N_Y	W3	

Table 14: **BG560 — XCV400E, XCV600E, XCV1000E, XCV1600E, XCV2000E**

Bank	Pin Description	Pin#	See Note
NA	GND	A29	
NA	GND	A32	
NA	GND	A33	
NA	GND	B1	
NA	GND	B6	
NA	GND	B9	
NA	GND	B15	
NA	GND	B23	
NA	GND	B27	
NA	GND	B31	
NA	GND	C2	
NA	GND	E1	
NA	GND	F32	
NA	GND	G2	
NA	GND	G33	
NA	GND	J32	
NA	GND	K1	
NA	GND	L2	
NA	GND	M33	
NA	GND	P1	
NA	GND	P33	
NA	GND	R32	
NA	GND	T1	
NA	GND	V33	
NA	GND	W2	
NA	GND	Y1	
NA	GND	Y33	
NA	GND	AB1	
NA	GND	AC32	
NA	GND	AD33	
NA	GND	AE2	
NA	GND	AG1	
NA	GND	AG32	
NA	GND	AH2	
NA	GND	AJ33	
NA	GND	AL32	
NA	GND	AM3	
NA	GND	AM7	
NA	GND	AM11	
NA	GND	AM19	
NA	GND	AM25	
NA	GND	AM28	
NA	GND	AM33	
NA	GND	AN1	
NA	GND	AN2	
NA	GND	AN5	
NA	GND	AN10	
NA	GND	AN14	
NA	GND	AN16	
NA	GND	AN20	
NA	GND	AN22	
NA	GND	AN27	
NA	GND	AN33	

Notes:

1. V_{REF} or I/O option only in the XCV2000E; otherwise, I/O option only.
2. V_{REF} or I/O option only in the XCV1600E & 2000E; otherwise, I/O option only.
3. V_{REF} or I/O option only in the XCV1000E, 1600E, & 2000E; otherwise, I/O option only.
4. V_{REF} or I/O option only in the XCV600E, 1000E, 1600E, & 2000E; otherwise, I/O option only.

Table 15: **BG560 Differential Pin Pair Summary XCV400E, XCV600E, XCV1000E, XCV1600E, XCV2000E**

Pair	Bank	P Pin	N Pin	AO	Other Functions
171	7	J33	M29	√	-
172	7	K31	L30	√	VREF
173	7	H33	L29	4	-
174	7	H32	J31	18	VREF
175	7	H31	K29	14	-
176	7	G32	J30	20	VREF
177	7	G31	J29	√	VREF
178	7	E32	E33	15	-
179	7	F31	H29	14	-
180	7	E31	D32	15	VREF
181	7	C33	G29	14	-
182	7	D31	F30	14	VREF

Notes:

1. AO in the XCV1600E.
2. AO in the XCV2000E.
3. AO in the XCV1600E, 2000E.
4. AO in the XCV1000E, 1600E.
5. AO in the XCV1000E, 2000E.
6. AO in the XCV1000E.
7. AO in the XCV1000E, 1600E, 2000E.
8. AO in the XCV600E, 1600E.
9. AO in the XCV400E, 600E, 1600E.
10. AO in the XCV400E, 600E, 1000E, 2000E.
11. AO in the XCV400E, 600E, 1000E.
12. AO in the XCV400E, 1000E, 2000E.
13. AO in the XCV400E, 600E, 1000E, 1600E.
14. AO in the XCV400E, 1000E, 1600E.
15. AO in the XCV600E, 1000E, 2000E.
16. AO in the XCV600E, 2000E.
17. AO in the XCV400E, 600E, 1600E, 2000E.
18. AO in the XCV600E, 1000E, 1600E, 2000E.
19. AO in the XCV400E, 600E, 2000E.
20. AO in the XCV400E, 1000E.

FG256 Fine-Pitch Ball Grid Array Packages

XCV50E, XCV100E, XCV200E, and XCV300E devices in FG256 fine-pitch Ball Grid Array packages have footprint compatibility. Pins labeled I0_VREF can be used as either in all parts unless device-dependent as indicated in the footnotes. If the pin is not used as V_{REF}, it can be used as general I/O. Immediately following Table 16, see Table 17 for Differential Pair information.

Table 16: **FG256 Package — XCV50E, XCV100E, XCV200E, XCV300E**

Bank	Pin Description	Pin #
0	GCK3	B8
0	IO	B3
0	IO	E7
0	IO	D8
0	IO_L0N_Y	C5
0	IO_VREF_L0P_Y	A3[2]
0	IO_L1N_YY	D5
0	IO_L1P_YY	E6
0	IO_VREF_L2N_YY	B4
0	IO_L2P_YY	A4
0	IO_L3N_Y	D6
0	IO_L3P_Y	B5
0	IO_VREF_L4N_YY	C6[1]
0	IO_L4P_YY	A5
0	IO_L5N_YY	B6
0	IO_L5P_YY	C7
0	IO_L6N_Y	D7
0	IO_L6P_Y	C8
0	IO_VREF_L7N_Y	B7
0	IO_L7P_Y	A6
0	IO_LVDS_DLL_L8N	A7
1	GCK2	C9
1	IO	B10
1	IO_LVDS_DLL_L8P	A8
1	IO_L9N_Y	D9
1	IO_L9P_Y	A9
1	IO_L10N_Y	E10
1	IO_VREF_L10P_Y	B9

Table 21: **FG676 Differential Pin Pair Summary XCV400E, XCV600E**

Pair	Bank	P Pin	N Pin	AO	Other Functions
52	2	G24	H22	√	-
53	2	J21	G25	2	-
54	2	G26	J22	1	VREF
55	2	H24	J23	√	-
56	2	J24	K20	√	VREF
57	2	K22	K21	√	D2
58	2	H25	K23	√	-
59	2	L20	J26	2	-
60	2	K25	L22	1	-
61	2	L21	L23	1	-
62	2	M20	L24	1	-
63	2	M23	M22	√	D3
64	2	L26	M21	√	-
65	2	N19	M24	2	-
66	2	M26	N20	1	VREF
67	2	N24	N21	√	-
68	2	N23	N22	√	-
69	3	P21	P23	√	-
70	3	P22	R25	1	VREF
71	3	P19	P20	2	-
72	3	R21	R22	√	-
73	3	R24	R23	√	VREF
74	3	T24	R20	1	-
75	3	T22	U24	1	-
76	3	T23	U25	1	-
77	3	T21	U20	2	-
78	3	U22	V26	√	-
79	3	T20	U23	√	D5
80	3	V24	U21	√	VREF
81	3	V23	W24	√	-
82	3	V22	W26	1	VREF
83	3	Y25	V21	2	-
84	3	V20	AA26	√	-
85	3	Y24	W23	√	VREF

Table 21: **FG676 Differential Pin Pair Summary XCV400E, XCV600E**

Pair	Bank	P Pin	N Pin	AO	Other Functions
86	3	AA24	Y23	1	-
87	3	AB26	W21	2	-
88	3	Y22	W22	1	VREF
89	3	AA23	AB24	2	-
90	3	W20	AC24	√	-
91	3	AB23	Y21	√	INIT
92	4	AC22	AD26	√	-
93	4	AD23	AA20	1	-
94	4	Y19	AC21	√	-
95	4	AD22	AB20	√	VREF
96	4	AE22	Y18	NA	-
97	4	AF22	AA19	NA	-
98	4	AD21	AB19	√	VREF
99	4	AC20	AA18	√	-
100	4	AC19	AD20	1	-
101	4	AF20	AB18	1	VREF
102	4	AD19	Y17	NA	-
103	4	AE19	AD18	NA	VREF
104	4	AF19	AA17	√	-
105	4	AC17	AB17	1	-
106	4	Y16	AE17	√	-
107	4	AF17	AA16	√	-
108	4	AD17	AB16	NA	-
109	4	AC16	AD16	√	-
110	4	AC15	Y15	√	VREF
111	4	AD15	AA15	√	-
112	4	W14	AB15	1	-
113	4	AF15	Y14	1	VREF
114	4	AD14	AB14	NA	-
115	5	AC14	AF13	NA	IO_LVDS_DLL
116	5	AA13	AF12	1	VREF
117	5	AC13	W13	1	-
118	5	AA12	AD12	√	-
119	5	AC12	AB12	√	VREF

FG680 Fine-Pitch Ball Grid Array Package

XCV600E, XCV1000E, XCV1600E, and XCV2000E devices in the FG680 fine-pitch Ball Grid Array package have footprint compatibility. Pins labeled IO_VREF can be used as either in all parts unless device-dependent as indicated in the footnotes. If the pin is not used as V_{REF}, it can be used as general I/O. Immediately following Table 22, see Table 23 for Differential Pair information.

Table 22: **FG680 - XCV600E, XCV1000E, XCV1600E, XCV2000E**

Bank	Pin Description	Pin #
0	GCK3	A20
0	IO	D35
0	IO	B36
0	IO_L0N_Y	C35
0	IO_L0P_Y	A36
0	IO_VREF_L1N_Y	D34[1]
0	IO_L1P_Y	B35
0	IO_L2N_YY	C34
0	IO_L2P_YY	A35
0	IO_VREF_L3N_YY	D33
0	IO_L3P_YY	B34
0	IO_L4N	C33
0	IO_L4P	A34
0	IO_L5N_Y	D32
0	IO_L5P_Y	B33
0	IO_L6N_YY	C32
0	IO_L6P_YY	D31
0	IO_VREF_L7N_YY	A33
0	IO_L7P_YY	C31
0	IO_L8N_Y	B32
0	IO_L8P_Y	B31
0	IO_VREF_L9N_Y	A32[3]
0	IO_L9P_Y	D30
0	IO_L10N_YY	A31
0	IO_L10P_YY	C30
0	IO_VREF_L11N_YY	B30
0	IO_L11P_YY	D29
0	IO_L12N_Y	A30
0	IO_L12P_Y	C29
0	IO_L13N_Y	A29
0	IO_L13P_Y	B29
0	IO_VREF_L14N_YY	B28
0	IO_L14P_YY	A28
0	IO_L15N_YY	C28
0	IO_L15P_YY	B27
0	IO_L16N_Y	D27
0	IO_L16P_Y	A27
0	IO_L17N_Y	C27
0	IO_L17P_Y	B26
0	IO_L18N_YY	D26
0	IO_L18P_YY	C26
0	IO_VREF_L19N_YY	A26[1]
0	IO_L19P_YY	D25
0	IO_L20N_Y	B25
0	IO_L20P_Y	C25
0	IO_L21N_Y	A25
0	IO_L21P_Y	D24
0	IO_L22N_YY	A24
0	IO_L22P_YY	B23
0	IO_VREF_L23N_YY	C24
0	IO_L23P_YY	A23
0	IO_L24N_Y	B24
0	IO_L24P_Y	B22
0	IO_L25N_Y	E23
0	IO_L25P_Y	A22
0	IO_L26N_YY	D23
0	IO_L26P_YY	B21
0	IO_VREF_L27N_YY	C23
0	IO_L27P_YY	A21
0	IO_L28N_Y	E22
0	IO_L28P_Y	B20
0	IO_LVDS_DLL_L29N	C22
0	IO_VREF	D22[2]
1	GCK2	D21

Table 26: **FG900 — XCV600E, XCV1000E, XCV1600E**

Bank	Pin Description	Pin #
2	IO_L99P_YY	N26
2	IO_L99N_YY	P28
2	IO_L100P	P29
2	IO_L100N	N24
2	IO_L101P_YY	P22
2	IO_L101N_YY	R26
2	IO_VREF_L102P_YY	P25
2	IO_L102N_YY	R29
2	IO_L103P_YY	R21[4]
2	IO_L103N_YY	R28[3]
2	IO_VREF_L104P_YY	R25[2]
2	IO_L104N_YY	T30
2	IO_L105P_YY	P24[4]
2	IO_L105N_YY	R27[3]
2	IO_L106P	R24
3	IO	T22[4]
3	IO	T24[4]
3	IO	T26[4]
3	IO	T29[4]
3	IO	U26[5]
3	IO	V23[4]
3	IO	V25[4]
3	IO	V30[5]
3	IO	Y21[4]
3	IO	AA26[4]
3	IO	AA23[4]
3	IO	AB27[4]
3	IO	AB29[4]
3	IO	AC28[5]
3	IO	AD26[4]
3	IO	AD29[5]
3	IO	AE27[5]
3	IO_L106N	U29
3	IO_L107P_YY	R22
3	IO_VREF_L107N_YY	T27[2]
3	IO_L108P_YY	R23
3	IO_L108N_YY	T28
3	IO_L109P_YY	T21
3	IO_VREF_L109N_YY	T25
3	IO_L110P_YY	U28
3	IO_L110N_YY	U30
3	IO_L111P	T23
3	IO_L111N	U27
3	IO_L112P_YY	U25
3	IO_L112N_YY	V27
3	IO_D4_L113P_YY	U24
3	IO_VREF_L113N_YY	V29
3	IO_L114P	W30
3	IO_L114N	U22
3	IO_L115P_YY	U21
3	IO_L115N_YY	W29
3	IO_L116P_YY	V26
3	IO_L116N_YY	W27
3	IO_L117P	W26
3	IO_VREF_L117N	Y29[1]
3	IO_L118P_YY	W25
3	IO_L118N_YY	Y30
3	IO_L119P_Y	V24[4]
3	IO_L119N_Y	Y28[4]
3	IO_L120P_YY	AA30
3	IO_L120N_YY	W24
3	IO_L121P	AA29
3	IO_L121N	V20
3	IO_L122P	Y27[4]
3	IO_L122N	W23[4]
3	IO_L123P_YY	Y26
3	IO_D5_L123N_YY	AB30
3	IO_D6_L124P_YY	V21
3	IO_VREF_L124N_YY	AA28
3	IO_L125P_YY	Y25
3	IO_L125N_YY	AA27
3	IO_L126P_YY	W22
3	IO_L126N_YY	Y23

Table 26: **FG900 — XCV600E, XCV1000E, XCV1600E**

Bank	Pin Description	Pin #
6	IO	AC5[4]
6	IO	AD1[4]
6	IO	AE5[5]
6	IO_L212N_YY	AF3
6	IO_L212P_YY	AC6
6	IO_L213N	AH2[4]
6	IO_L213P	AG2[3]
6	IO_L214N	AB9
6	IO_L214P	AE4
6	IO_VREF_L215N_YY	AE3[1]
6	IO_L215P_YY	AH1
6	IO_L216N_Y	AB8[4]
6	IO_L216P_Y	AD6[3]
6	IO_L217N_YY	AG1
6	IO_L217P_YY	AA10
6	IO_VREF_L218N	AA9
6	IO_L218P	AD4
6	IO_L219N_YY	AD5
6	IO_L219P_YY	AD2
6	IO_L220N_YY	AD3
6	IO_L220P_YY	AF2
6	IO_L221N	AA8
6	IO_L221P	AA7
6	IO_VREF_L222N_YY	AF1
6	IO_L222P_YY	Y9
6	IO_L223N_YY	AB6
6	IO_L223P_YY	AC4
6	IO_L224N	AE1
6	IO_L224P	W8
6	IO_L225N_YY	Y8
6	IO_L225P_YY	AB4
6	IO_VREF_L226N_YY	AB3
6	IO_L226P_YY	W9
6	IO_L227N_YY	AA5[4]
6	IO_L227P_YY	W10[3]
6	IO_L228N_YY	AB1
6	IO_L228P_YY	V10
6	IO_L229N_YY	Y7[4]
6	IO_VREF_L229P_YY	AC1
6	IO_L230N	V11
6	IO_L230P	AA3
6	IO_L231N_YY	AA2[3]
6	IO_L231P_YY	U10[4]
6	IO_L232N	W7
6	IO_L232P	AA6
6	IO_L233N_YY	Y6
6	IO_L233P_YY	Y4
6	IO_L234N_Y	AA1[4]
6	IO_L234P_Y	V7[4]
6	IO_L235N_YY	Y3
6	IO_L235P_YY	Y2
6	IO_VREF_L236N	Y5[1]
6	IO_L236P	W5
6	IO_L237N_YY	W4
6	IO_L237P_YY	W6
6	IO_L238N_YY	V6
6	IO_L238P_YY	W2
6	IO_L239N	U9
6	IO_L239P	V4
6	IO_VREF_L240N_YY	AB2
6	IO_L240P_YY	T8
6	IO_L241N_YY	U5
6	IO_L241P_YY	W1
6	IO_L242N	Y1
6	IO_L242P	T9
6	IO_L243N_YY	T7
6	IO_L243P_YY	U3
6	IO_VREF_L244N_YY	T5
6	IO_L244P_YY	V2
6	IO_L245N_YY	R9[4]
6	IO_L245P_YY	T6[3]
6	IO_VREF_L246N_YY	T4[2]
6	IO_L246P_YY	U2
6	IO_L247N	T1

Table 28: **FG1156 — XCV1000E, XCV1600E, XCV2000E, XCV2600E, XCV3200E**

Bank	Pin Description	Pin #
2	IO_L92N_Y	H29
2	IO_L93P_YY	J28[4]
2	IO_L93N_YY	E33[5]
2	IO_L94P_YY	H28
2	IO_L94N_YY	H30
2	IO_L95P_Y	H32
2	IO_L95N_Y	K28
2	IO_L96P_Y	L27[4]
2	IO_L96N_Y	F33[5]
2	IO_L97P_Y	M26
2	IO_L97N_Y	E34
2	IO_VREF_L98P_YY	H31
2	IO_L98N_YY	G32
2	IO_L99P_YY	N25[4]
2	IO_L99N_YY	J31[5]
2	IO_L100P_YY	J30
2	IO_L100N_YY	G33
2	IO_VREF_L101P_Y	H34[2]
2	IO_L101N_Y	J29
2	IO_L102P	M27[4]
2	IO_L102N	H33[5]
2	IO_L103P_Y	K29
2	IO_L103N_Y	J34
2	IO_VREF_L104P_YY	L29
2	IO_L104N_YY	J33
2	IO_L105P_YY	M28
2	IO_L105N_YY	K34
2	IO_L106P_Y	N27
2	IO_L106N_Y	L34
2	IO_VREF_L107P_YY	K33
2	IO_D1_L107N_YY	P26
2	IO_L108P_Y	R25
2	IO_L108N_Y	M34
2	IO_L109P_Y	L31
2	IO_L109N_Y	L33
2	IO_L110P_Y	P27
2	IO_L110N_Y	M33
2	IO_L111P	M31
2	IO_L111N	R26
2	IO_L112P_Y	N30
2	IO_L112N_Y	P28
2	IO_VREF_L113P_Y	N29
2	IO_L113N_Y	N33
2	IO_L114P_YY	T25[4]
2	IO_L114N_YY	N34[5]
2	IO_L115P_YY	P34
2	IO_L115N_YY	R27
2	IO_L116P_Y	P29
2	IO_L116N_Y	P31
2	IO_L117P_Y	P33[4]
2	IO_L117N_Y	T26[5]
2	IO_L118P_Y	R34
2	IO_L118N_Y	R28
2	IO_VREF_L119P_YY	N31
2	IO_D3_L119N_YY	N32
2	IO_L120P_YY	P30[4]
2	IO_L120N_YY	R33[5]
2	IO_L121P_YY	R29
2	IO_L121N_YY	T34
2	IO_L122P_Y	R30
2	IO_L122N_Y	T30
2	IO_L123P	T28[4]
2	IO_L123N	R31[5]
2	IO_L124P_Y	T29
2	IO_L124N_Y	U27
2	IO_VREF_L125P_YY	T31
2	IO_L125N_YY	T33
2	IO_L126P_YY	U28